

Contents

| | |
|---|------------------|
| <i>Preface</i> | <i>page</i> xiii |
| <i>Notation</i> | xv |
| Chapter 1 | |
| Trends in Microelectronics and Optoelectronics | 1 |
| <hr/> | |
| Chapter 2 | |
| Theoretical Basis of Nanoelectronics | 12 |
| <hr/> | |
| 2.1 Introduction | 12 |
| 2.2 Wave-Particle Duality in Quantum Physics | 13 |
| 2.3 Time and Length Scales | 15 |
| 2.3.1 Electron Fundamental Lengths in Solids | 15 |
| 2.3.2 Quantum and Classical Regimes of Electron Transport | 20 |
| 2.3.3 Time Scales and Temporal (Frequency) Regimes | 21 |
| 2.4 Schrödinger Equation | 23 |
| 2.4.1 Average Values of Physical Quantities | 29 |
| 2.4.2 Separation of Variables | 30 |
| 2.4.3 Variational Method | 32 |
| 2.4.4 Perturbation Methods | 33 |
| 2.5 Many-Particle Systems | 37 |
| 2.5.1 Spin and Electron Statistics | 37 |
| 2.5.2 Many-Particle Schrödinger Equation: Self-Consistent Potential | 40 |
| 2.6 An Electron in Crystalline Potential: Effective-Mass Approximation | 44 |
| 2.6.1 Bloch Functions | 45 |
| 2.6.2 Occupation of Energy Bands: Metals, Semiconductors, and Dielectrics | 47 |
| 2.6.3 Effective Masses | 50 |
| 2.6.4 The Envelope Function | 53 |
| 2.7 Quantum Electron Transport: Landauer Formula | 55 |
| 2.8 Boltzmann Transport Equation | 61 |
| 2.9 Local Approximations for Electron Transport | 64 |
| 2.9.1 Electron Mobility and Diffusion Coefficient | 64 |
| 2.9.2 Electron Temperature (Hydrodynamic) Approximation | 67 |
| 2.9.3 Drift-Diffusion Model | 70 |

vi Contents

| | |
|--|------------|
| 2.10 Closing Remarks | 70 |
| PROBLEMS | 71 |
| Chapter 3 | |
| Electrons in Quantum Structures | 73 |
| 3.1 Introduction | 73 |
| 3.2 Quantum Wells | 75 |
| 3.2.1 Density of States of a Two-Dimensional Electron Gas | 81 |
| 3.2.2 Quantum Effects in a Continuum-Electron Spectrum | 83 |
| 3.2.3 Two-Dimensional Electron Motion in a Smooth Potential | 85 |
| 3.3 Quantum Wires | 87 |
| 3.3.1 Wave Functions and Energy Subbands | 88 |
| 3.3.2 Density of States for a One-Dimensional Electron Gas | 90 |
| 3.4 Quantum Dots | 91 |
| 3.4.1 Wave Functions and Energy Levels | 91 |
| 3.4.2 Density of States for Zero-Dimensional Electrons | 94 |
| 3.5 Coupling between Quantum Wells | 96 |
| 3.6 Superlattices | 99 |
| 3.6.1 Density of States | 104 |
| 3.7 Excitons in Quantum Structures | 106 |
| 3.7.1 Excitons | 106 |
| 3.7.2 Excitons in Quantum Wells | 110 |
| 3.8 Coulomb Bound States and Defects in Quantum Structures | 115 |
| 3.8.1 Coulomb Bound States of Impurities | 116 |
| 3.8.2 Interfacial Defects | 119 |
| 3.9 Closing Remarks | 123 |
| PROBLEMS | 125 |
| Chapter 4 | |
| Properties of Particular Quantum Structures | 126 |
| 4.1 Introduction | 126 |
| 4.2 Energy Spectra of Some Semiconductor Materials | 127 |
| 4.2.1 Symmetry of Crystals and General Properties of Electron Spectra | 127 |
| 4.2.2 Band Structures of Semiconductor Alloys | 132 |
| 4.2.3 Electron Affinities: Energy-Band Discontinuities of Heterostructures | 134 |
| 4.3 Lattice-Matched and Pseudomorphic Heterostructures | 136 |
| 4.3.1 Lattice-Matched and Lattice-Mismatched Materials | 138 |
| 4.3.2 Lattice-Matched Heterostructures | 141 |
| 4.3.3 Strained Pseudomorphic Structures | 143 |
| 4.3.4 Si/Ge Strained Heterostructures | 146 |
| 4.4 Single-Heterojunction Devices: Selective Doping | 151 |

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Table of Contents

[More information](#)

Contents vii

| | | |
|--|---|------------|
| 4.4.1 | Introduction | 151 |
| 4.4.2 | Metal-Oxide-Semiconductor Structures | 153 |
| 4.4.3 | Single Modulation-Doped Heterojunction | 155 |
| 4.4.4 | Basic Equations and Quantitative Results for a Single Heterostructure | 156 |
| 4.4.5 | Simple Analytical Estimates for a Selectively Doped Single Heterostructure | 161 |
| 4.4.6 | Numerical Analysis of a Modulation-Doped Single Heterojunction | 163 |
| 4.4.7 | Control of Charge Transfer | 167 |
| 4.5 | Modulation-Doped Quantum Structures | 171 |
| 4.5.1 | Modulation-Doped Quantum Wells | 171 |
| 4.5.2 | <i>n-i-p</i> Structures | 176 |
| 4.5.3 | Delta Doping | 180 |
| 4.6 | Closing Remarks | 182 |
| | PROBLEMS | 184 |
| Chapter 5 | | |
| Lattice Vibrations in Quantum Structures | | 185 |
| 5.1 | Introduction | 185 |
| 5.2 | Vibrations of Atomic Linear Chains | 186 |
| 5.2.1 | Monoatomic Chain | 186 |
| 5.2.2 | Diatomic Chain | 189 |
| 5.3 | Normal Coordinates. Three-Dimensional Case | 192 |
| 5.4 | Phonons | 196 |
| 5.5 | Acoustic Vibrations in Quantum Structures | 199 |
| 5.5.1 | Acoustic Modes in the Long-Wavelength Limit | 199 |
| 5.5.2 | Acoustic-Mode Localization in Heterostructures with Quantum Wells and Wires | 202 |
| 5.6 | Short-Wavelength and Optical Vibrations in Quantum Structures | 218 |
| 5.6.1 | Qualitative Analysis of Short-Wavelength Vibrations | 218 |
| 5.6.2 | Optical Vibrations in Polar Crystals | 223 |
| 5.7 | Closing Remarks | 231 |
| | PROBLEMS | 233 |
| Chapter 6 | | |
| Electron Scattering in Quantum Structures | | 235 |
| 6.1 | Introduction | 235 |
| 6.2 | Elastic Scattering in Two-Dimensional Electron Systems | 239 |
| 6.3 | Screening of a Two-Dimensional Electron Gas | 242 |
| 6.4 | Scattering by Remote Ionized Impurities | 246 |
| 6.5 | Scattering by Interface Roughness | 249 |
| 6.6 | Electron-Phonon Interaction | 253 |

viii Contents

| | | |
|------------------|--|------------|
| 6.6.1 | Transitions due to Electron–Phonon Interactions | 253 |
| 6.6.2 | Short-Range and Long-Range Electron–Phonon Interactions | 255 |
| 6.6.3 | The Interaction with Different Phonon Modes | 256 |
| 6.7 | Interaction with Acoustic Phonons | 260 |
| 6.8 | Interaction with Optical Phonons | 267 |
| 6.9 | Scattering of Electrons by Acoustic Phonons in Quantum Wells and Wires | 273 |
| 6.9.1 | Quantum Wells | 276 |
| 6.9.2 | Quantum Wires | 281 |
| 6.9.3 | Free-Standing Quantum Structures | 281 |
| 6.10 | Scattering of Electrons by Optical Phonons in Quantum Wells and Wires | 284 |
| 6.10.1 | Quantum Wells | 284 |
| 6.10.2 | Quantum Wires | 288 |
| 6.11 | Closing Remarks | 290 |
| | PROBLEMS | 292 |
| Chapter 7 | | |
| | Parallel Transport in Quantum Structures | 295 |
| 7.1 | Introduction | 295 |
| 7.2 | Linear Electron Transport | 297 |
| 7.3 | High-Field Electron Transport | 303 |
| 7.3.1 | Hot, Warm, and Cold Electrons | 304 |
| 7.3.2 | Velocity Saturation | 307 |
| 7.3.3 | Transient Overshoot Effect | 311 |
| 7.3.4 | Gunn Effect | 312 |
| 7.3.5 | Nonequilibrium Phonons | 315 |
| 7.3.6 | Hot-Electron Size Effect | 316 |
| 7.4 | Hot Electrons in Quantum Structures | 317 |
| 7.4.1 | Nonlinear Transport in Two-Dimensional Electron Gases | 317 |
| 7.4.2 | Nonlinear Electron Transport in Quantum Wires | 319 |
| 7.4.3 | Real-Space Transfer of Hot Electrons | 324 |
| 7.4.4 | Other Effects of High-Field Electron Transport in Quantum Structures | 326 |
| 7.5 | Closing Remarks | 328 |
| | PROBLEMS | 330 |
| Chapter 8 | | |
| | Perpendicular Transport in Quantum Structures | 333 |
| 8.1 | Introduction | 333 |
| 8.2 | Double-Barrier Resonant-Tunneling Structures | 333 |
| 8.2.1 | Coherent Tunneling | 336 |

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Vladimir V. Mitin, Viatcheslav Kochelap and Michael A. Stroscio

Table of Contents

[More information](#)

| | Contents ix |
|---|-------------|
| 8.2.2 Sequential Tunneling | 340 |
| 8.2.3 Comparison of Two Mechanisms of Resonant Tunneling | 342 |
| 8.2.4 Negative Differential Resistance under Resonant Tunneling | 343 |
| 8.3 Superlattices and Ballistic-Injection Devices | 346 |
| 8.3.1 Negative Differential Resistance and Transconductance of Devices with Ballistic Superlattices | 346 |
| 8.3.2 Bloch Oscillations | 350 |
| 8.3.3 Wannier–Stark Energy Ladder | 352 |
| 8.3.4 Negative Differential Resistance in Superlattices for Electron-Collision Regimes | 355 |
| 8.3.5 Ballistic-Injection Devices | 356 |
| 8.4 Single-Electron Transfer and Coulomb Blockade | 357 |
| 8.5 Closing Remarks | 359 |
| PROBLEMS | 361 |
| Chapter 9 | |
| Electronic Devices Based on Quantum Heterostructures | 362 |
| 9.1 Introduction | 362 |
| 9.2 Field-Effect Transistors | 367 |
| 9.2.1 Principle of Field-Effect-Transistor Operation | 367 |
| 9.2.2 Amplification and Switching | 372 |
| 9.2.3 Heterostructure Field-Effect Transistors | 377 |
| 9.3 Velocity-Modulation and Quantum-Interference Transistors | 385 |
| 9.3.1 Velocity-Modulation Transistors | 385 |
| 9.3.2 Quantum-Interference Transistors | 389 |
| 9.4 Bipolar Heterostructure Transistors | 394 |
| 9.4.1 p - n Junctions and Homostructure Bipolar Transistors | 394 |
| 9.4.2 Heterostructure Bipolar Transistors | 408 |
| 9.5 Si/SiGe Heterostructure Bipolar Transistors | 412 |
| 9.6 Hot-Electron Transistors | 416 |
| 9.6.1 Ballistic-Injection Devices | 416 |
| 9.6.2 Real-Space Transfer Devices | 420 |
| 9.7 Applications of the Resonant-Tunneling Effect | 425 |
| 9.7.1 Resonant-Tunneling Oscillators | 425 |
| 9.7.2 Resonant-Tunneling Diode as Frequency Multiplier | 431 |
| 9.7.3 Resonant-Tunneling Transistors | 435 |
| 9.8 Circuit Applications of Resonant-Tunneling Transistors | 446 |
| 9.8.1 Multiplex Current-Voltage Characteristics and Multivalued Logic Applications | 448 |
| 9.9 Closing Remarks | 452 |
| PROBLEMS | 455 |

x Contents

| | |
|--|------------|
| Chapter 10 | |
| Optics of Quantum Structures | 456 |
| 10.1 Introduction | 456 |
| 10.2 Electromagnetic Waves and Photons | 457 |
| 10.2.1 Electromagnetic Fields, Modes, and Photons in Free Space | 457 |
| 10.2.2 Photons in Nonuniform Dielectric Media | 460 |
| 10.2.3 Optical Resonators | 461 |
| 10.2.4 Photon Statistics | 464 |
| 10.3 Light Interaction with Matter: Phototransitions | 464 |
| 10.3.1 Photon Absorption and Emission | 464 |
| 10.3.2 Calculation of Phototransition Probabilities | 467 |
| 10.4 Optical Properties of Bulk Semiconductors | 470 |
| 10.4.1 Interband Emission and Absorption in Bulk Semiconductors | 471 |
| 10.4.2 Spectral Density of Spontaneous Emission | 479 |
| 10.4.3 Phototransitions in III–V Compounds | 480 |
| 10.4.4 Excitonic Effects | 484 |
| 10.4.5 Refractive Index | 484 |
| 10.5 Optical Properties of Quantum Structures | 487 |
| 10.5.1 Electrodynamics of Heterostructures | 487 |
| 10.5.2 Light Absorption by Confined Electrons | 490 |
| 10.5.3 Effects of Complex Valence Bands of III–V Compounds | 494 |
| 10.5.4 Other Factors Affecting the Interband Optical Spectra | 496 |
| 10.5.5 Polarization Effects | 499 |
| 10.6 Intraband Transitions in Quantum Structures | 500 |
| 10.6.1 Intraband Absorption and Conservation Laws | 500 |
| 10.6.2 Probability of Intersubband Phototransitions | 502 |
| 10.6.3 Probability of Phototransitions to Extended States | 508 |
| 10.7 Closing Remarks | 511 |
| PROBLEMS | 512 |
| Chapter 11 | |
| Electro-Optics and Nonlinear Optics | 513 |
| 11.1 Introduction | 513 |
| 11.2 Electro-Optics in Semiconductors | 513 |
| 11.2.1 Electro-Optical Effect in Conventional Materials | 513 |
| 11.2.2 Electro-Optical Effect in Quantum Wells | 518 |
| 11.2.3 Electro-Optical Effect in Superlattices | 524 |
| 11.2.4 Terahertz Coherent Oscillations of Electrons in an Electric Field | 529 |

| | Contents xi |
|---|-------------|
| 11.3 Nonlinear Optics in Heterostructures | 532 |
| 11.3.1 Linear and Nonlinear Optics | 532 |
| 11.3.2 Optical Nonlinearities in Quantum Wells | 534 |
| 11.3.3 Virtual Field-Induced Mechanism of Nonlinear Optical Effects | 535 |
| 11.3.4 Nonlinear Optical Effects due to Generation of Excitons and Electron–Hole Plasma | 536 |
| 11.3.5 Nonlinear Effects Induced by Nonthermalized Electron–Hole Plasma | 542 |
| 11.3.6 Optical Bistability | 543 |
| 11.3.7 Applications of Nonlinear Optical Effects in Quantum Wells | 548 |
| 11.4 Closing Remarks | 553 |
| PROBLEMS | 555 |
| Chapter 12 | |
| Optical Devices Based on Quantum Structures | 556 |
| 12.1 Introduction | 556 |
| 12.2 Light Amplification in Semiconductors | 556 |
| 12.2.1 Criteria for Light Amplification | 557 |
| 12.2.2 Estimates of Light Gain | 560 |
| 12.2.3 Methods of Pumping | 562 |
| 12.2.4 Motivations for Using Heterostructures for Light Amplifications | 566 |
| 12.2.5 Light Amplification in Quantum Wells and Quantum Wires | 570 |
| 12.3 Light-Emitting Diodes and Lasers | 574 |
| 12.3.1 Light-Emitting Diodes | 574 |
| 12.3.2 Amplification, Feedback, and Laser Oscillations | 579 |
| 12.3.3 Laser Output Power and Emission Spectra | 581 |
| 12.3.4 Modulation of the Laser Output | 584 |
| 12.3.5 Quantum-Well Lasers | 587 |
| 12.3.6 Surface-Emitting Lasers | 592 |
| 12.3.7 Quantum-Wire Lasers | 594 |
| 12.3.8 Blue Quantum-Well Lasers | 599 |
| 12.3.9 Unipolar Intersubband Quantum-Cascade Laser | 602 |
| 12.4 Self-Electro-Optic-Effect Devices | 609 |
| 12.4.1 Resistor SEED | 609 |
| 12.4.2 Symmetric SEED | 611 |
| 12.5 Photodetectors on Intraband Phototransitions | 614 |
| 12.5.1 Photoconductive Detectors | 615 |

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Table of Contents

[More information](#)**xii Contents**

| | | |
|--------|--|-----|
| 12.5.2 | Intraband Phototransitions and Electron Transport in Multiple-Quantum-Well Structures | 618 |
| 12.5.3 | Simple Model of Multiple-Quantum-Well Photodetectors | 624 |
| 12.6 | Closing Remarks | 631 |
| | PROBLEMS | 633 |
| | <i>Index</i> | 635 |